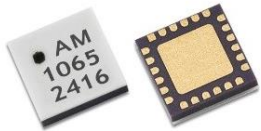


AM1065 – Amplifier

DC to 8 GHz Bypassable

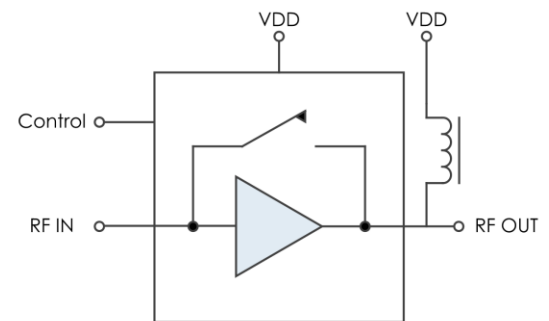


The AM1065 is a high dynamic range bypassable DC-coupled amplifier covering up to 8 GHz. The device exhibits low bypass insertion loss, and a moderate positive gain-slope providing frequency equalization useful in many broadband applications. Packaged in a 4mm QFN or a shielded module with internal 50 Ω matching and requiring a single positive control voltage, the AM1065 represents a dramatic size reduction over a discrete implementation of a bypassable amplifier.

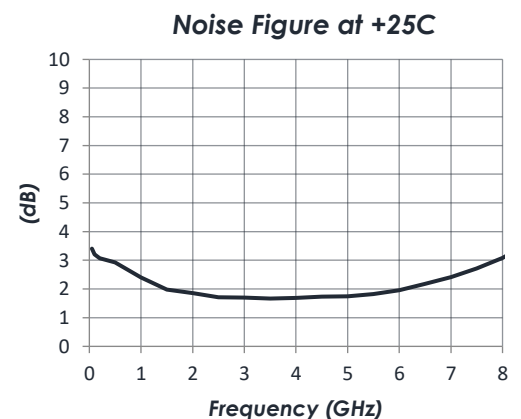
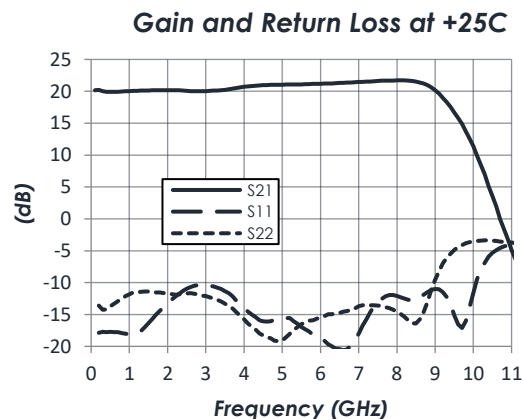
FEATURES

- 20 dB Gain
- 1.25 dB Bypass Insertion Loss
- 2.0 dB Noise Figure
- +31 dBm OIP3
- +18 dBm P1dB
- +20 dBm PSat
- +5.0V, 72/1 mA (Gain/Bypass)
- +3.0V to +5.0V Supply Range
- +3.3V or +5V Logic Compatible
- 4mm QFN Package

FUNCTIONAL DIAGRAM



CHARACTERISTIC PERFORMANCE



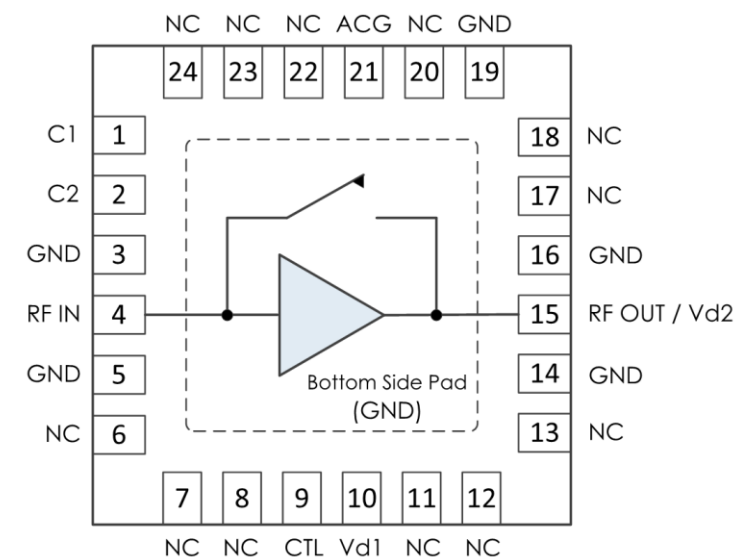
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REVISION HISTORY

Date	Revision	Notes
April 24, 2018	7	Updated to new datasheet format and added more comprehensive data about part
July 16, 2018	8	C3 value in Typical Application updated. Max RF Input Power updated.
May 17, 2019	9	Additional Detail Added to Timing Section. Various Plots, Specifications, Typical Application, and Compliance Information Updated
July 26, 2019	10	Added current draw in bypass mode. New RF shielded module available.
November 26, 2019	10A	Updated Description to include shielded module packaging
February 5, 2020	11	Updated module drawing with correct RF I/O labels
May 15, 2020	12	Package and module information moved to main product page
October 7, 2020	13	Control pin current drive level added. MSL corrected.
November 7, 2024	14	Changed to Mercury branding. No content changes.

PIN LAYOUT AND DEFINITIONS



Pin	Name	Function
1	C1	External Capacitor Connection 1
2	C2	External Capacitor Connection 2
3	GND	Ground – Common
4	RF IN	RF Input – 50 ohms – DC Coupled, External DC Block Required
5	GND	Ground – Common
6-8	NC	Not Connected *
9	CTL	Bypass/Amplifier Mode Control
10	VD1	DC Power Input
11-13	NC	Not Connected *
14	GND	Ground – Common
15	RF OUT/VD2	RF Output and DC Power Input – 50 ohms – DC Coupled, External DC Block Required
16	GND	Ground – Common
17, 18	NC	Not Connected *
19	GND	Ground – Common
20	NC	Not Connected *
21	ACG	AC Ground
22-24	NC	Not Connected *
Bottom Pad	GND	Ground – Common

* NC pins may be grounded or left open.

SPECIFICATIONS

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	0.0 V	+6.0 V
RF Input Power		+25 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Devices subjected to conditions outside of what is recommended for extended periods may affect device reliability.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 1	

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+4.7 V	+5.2 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

Thermal Resistance (°C / W)	
Junction to Case Thermal Resistance (θ_{JC})	63.0



Mercury products are electrostatic sensitive.
Follow safe handling practices to avoid damage.

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Param	Testing Conditions	Min	Typical	Max.
DC Supply Voltage		+3.0 V	+4.7 V	+5.2 V
DC Supply Current	VDD = +5.0 V, Amp On	64 mA	72 mA	80 mA
	VDD = +3.3 V, Amp On	28 mA	32 mA	36 mA
	VDD = +5.0 V, Amp Byp.		1 mA	
	VDD = +3.3 V, Amp Byp.		< 1mA	
Power Dissipated	VDD = +5.0 V, Amp On	0.32 W	0.36 W	0.40 W
	VDD = +3.3 V, Amp On	0.09 W	0.11 W	0.12 W
Logic Level Low		-0.1 V		+0.4 V
Logic Level High		+2.2 V		+VDD
Control Current	CTL = +3.3V		115 µA	
	CTL = +5.0V		200 µA	

State Table

CTL	Amplifier
High	Enabled
Low	Bypassed

RF Performance

(T = 25 °C unless otherwise specified)

Param	Testing Conditions	Min	Typical	Max.
Frequency Range		DC		8 GHz
Gain	VDD = +5.0 V		20 dB	
	VDD = +3.3 V		19 dB	
Return Loss	VDD = +5.0 V		13 dB	
Bypass Insertion Loss	VDD = +5.0 V		1.25 dB	
Output IP3	VDD = +5.0 V		+31 dBm	
Output P1dB	VDD = +5.0 V		+18 dBm	
Noise Figure	VDD = +5.0 V		2.0 dB	

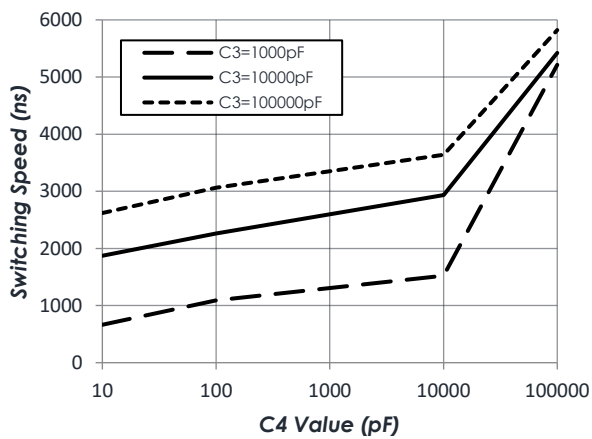
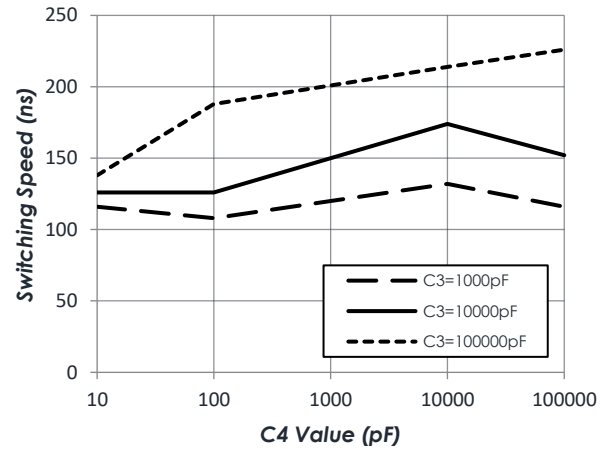
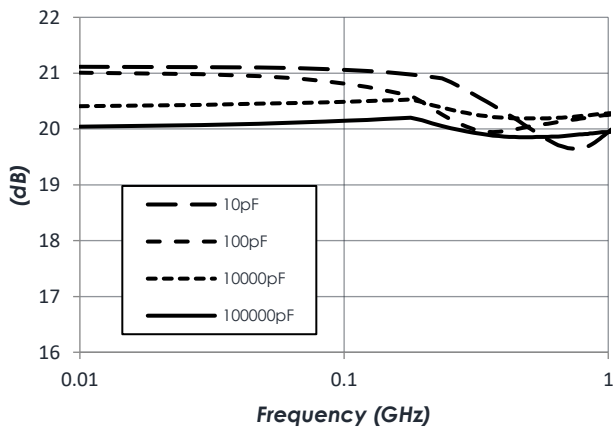
Timing Characteristics

(T = 25 °C, VDD = +3.3V, CTL = 0.0V / +3.3V)

Switching Time	Minimum	Typical ²	Maximum
Amp On → Amp Bypass)	125 ns	175 ns	300 ns
Amp Bypass → Amp On)	700 ns	3.8 μ s	7.0 μ s

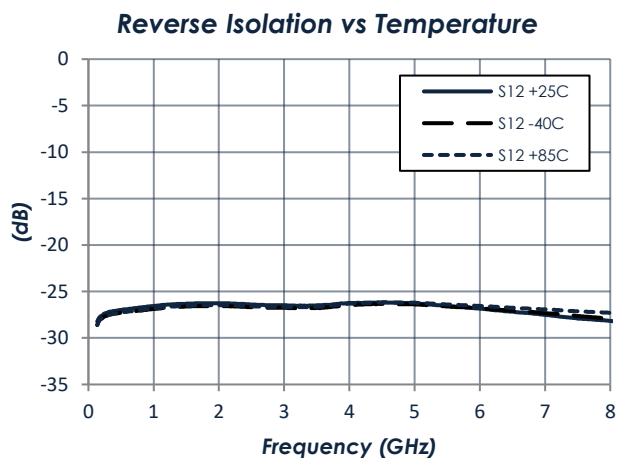
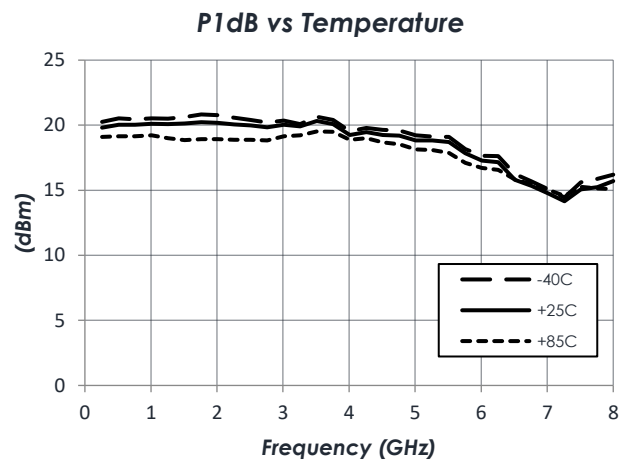
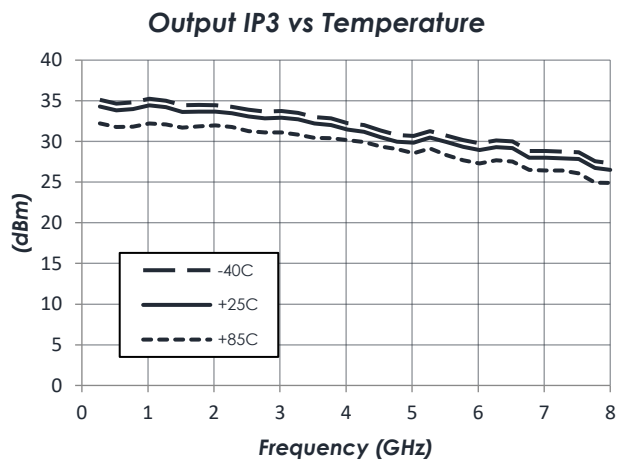
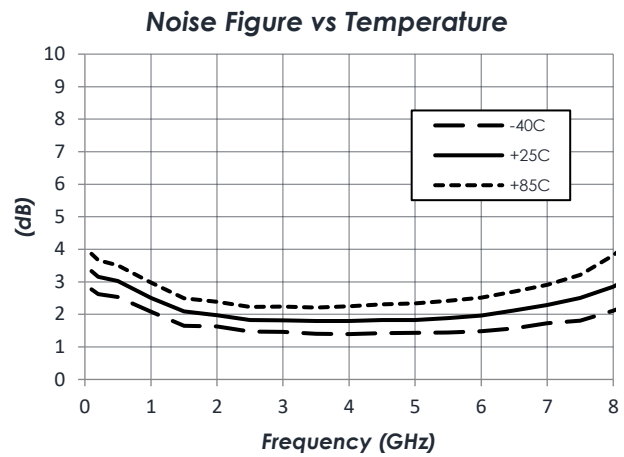
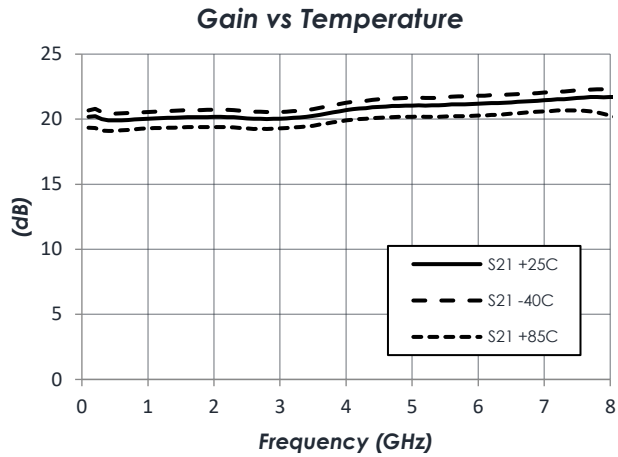
Notes:

1. Switching speeds measured as 50% trigger to 10%/90% RF respectively.
2. Typical measurements reflect switching speeds of amp as configured in Typical Application section.
3. To change times, alter value of C3 and C4 (see Typical Application section).

Bypass to Amp On vs Cap Values**Amp to Bypass vs Cap Values****Gain vs C4 Value**

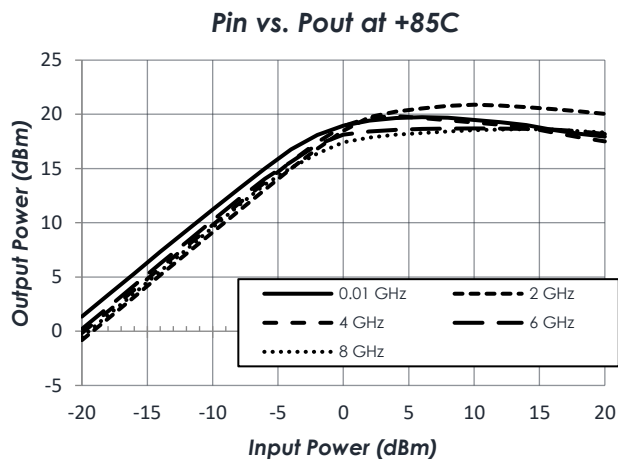
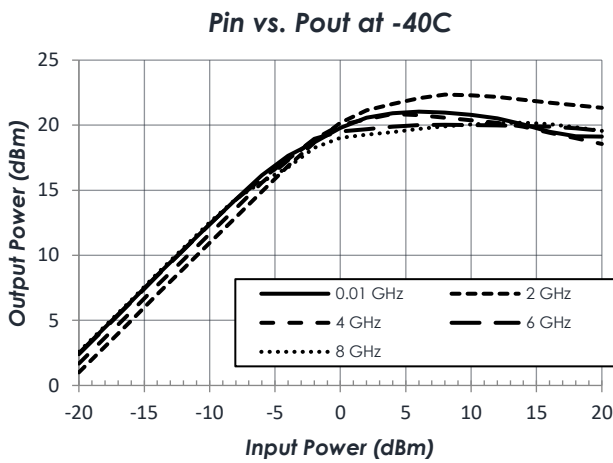
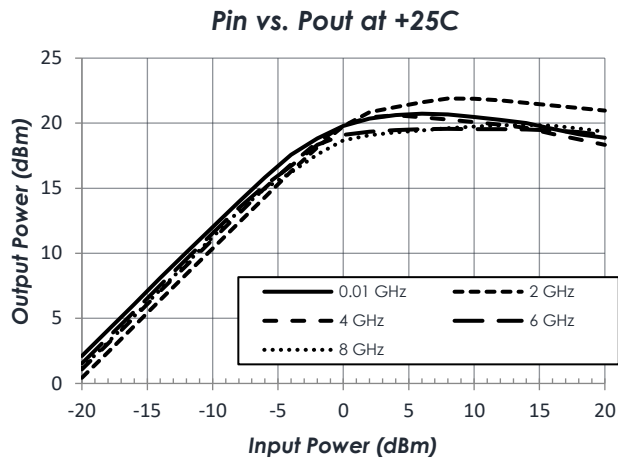
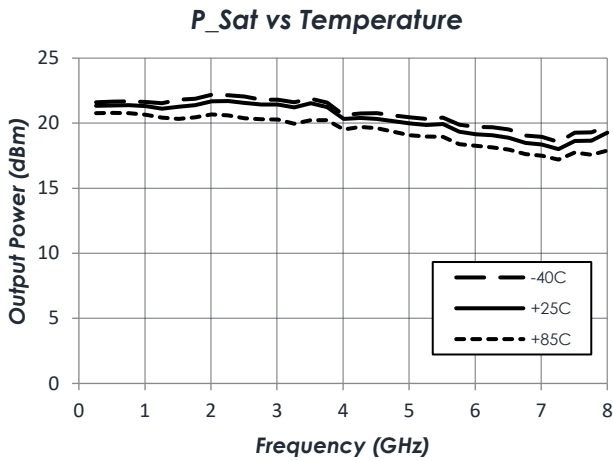
TYPICAL PERFORMANCE

(Amplifier Enabled, VDD = +5.0 V, ID = 72mA)



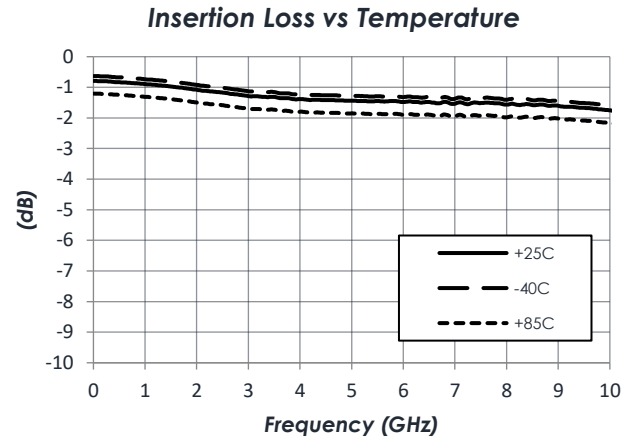
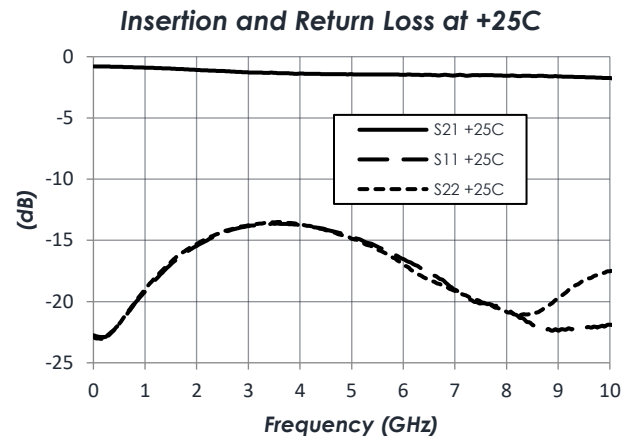
TYPICAL PERFORMANCE (continued)

(Amplifier Enabled, VDD = +5.0 V, ID = 72mA)



TYPICAL PERFORMANCE (CONTINUED)

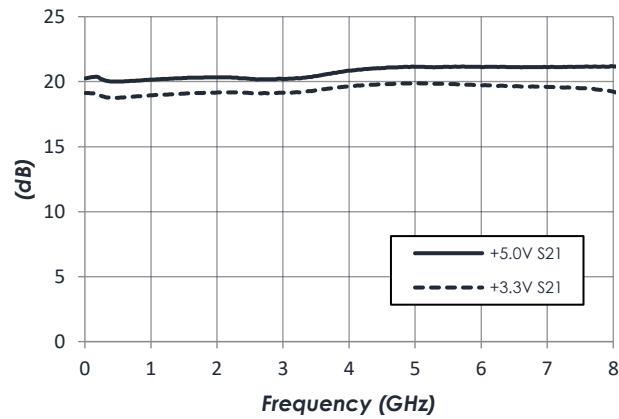
(Amplifier Bypass, VDD = +5.0 V, ID = 1mA)



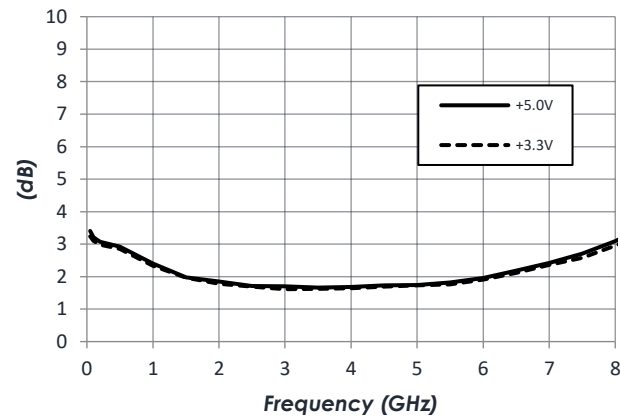
TYPICAL PERFORMANCE (CONTINUED)

(T = 25 °C, Amplifier Enabled unless otherwise specified)

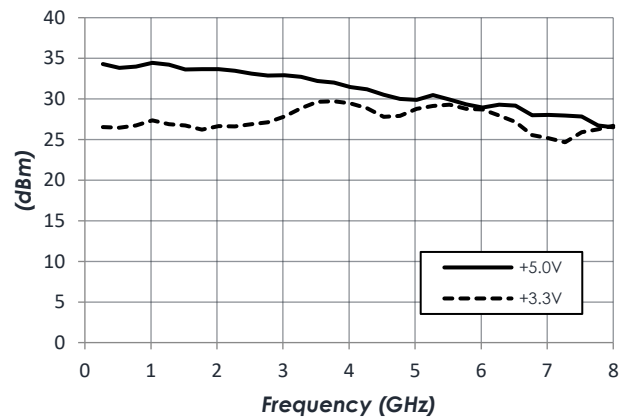
Gain vs VDD



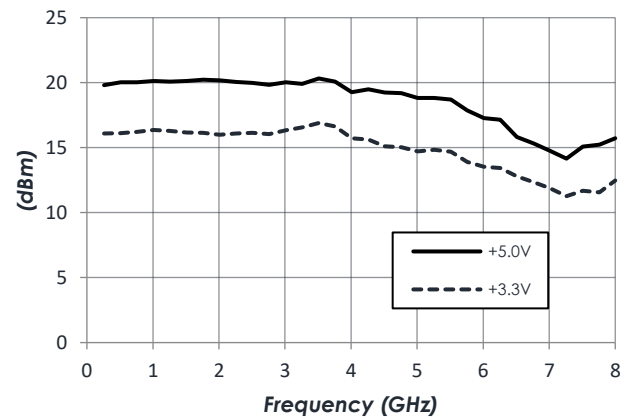
Noise Figure vs VDD



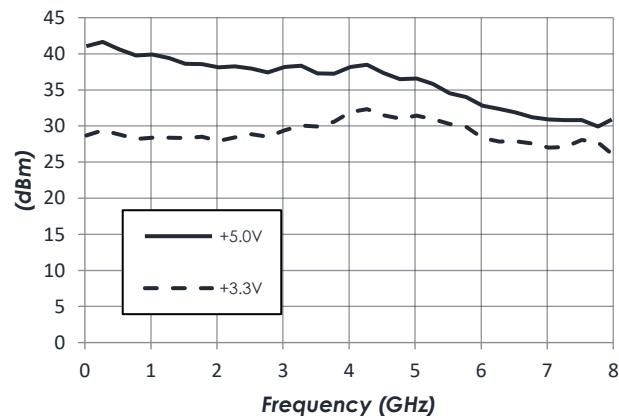
Output IP3 vs VDD



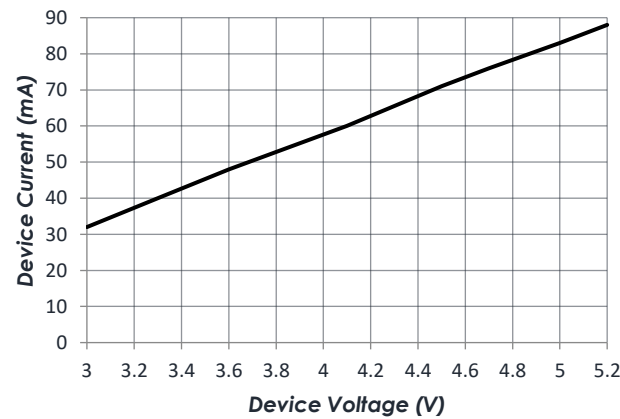
P1dB vs VDD



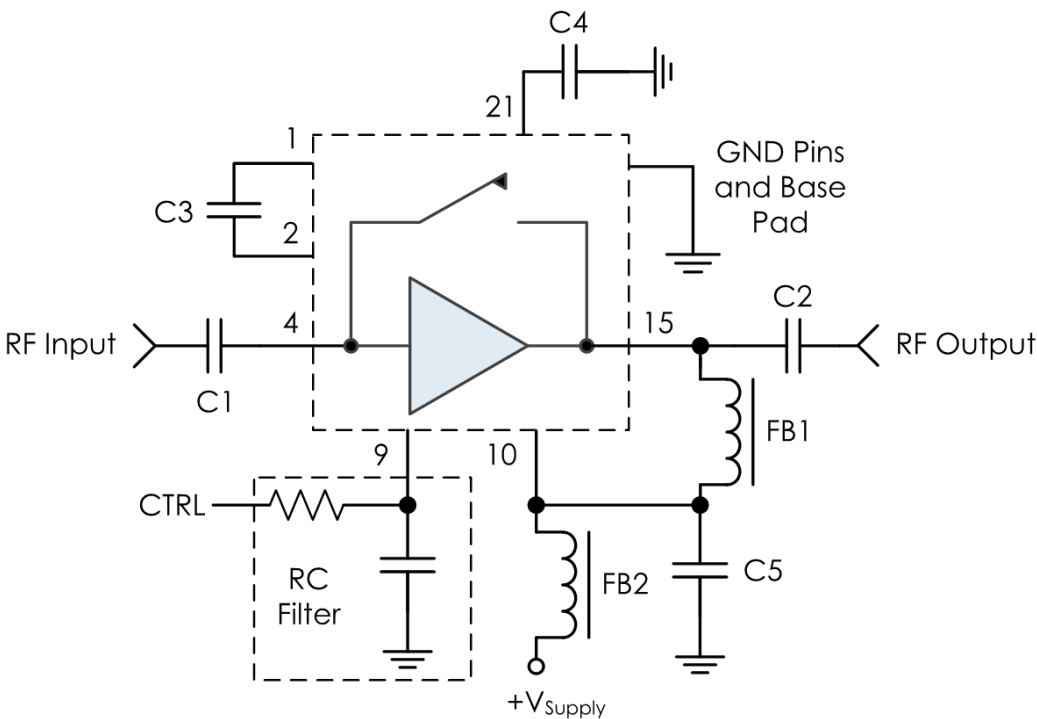
Output IP2 vs VDD



ID vs. VD2



TYPICAL APPLICATION



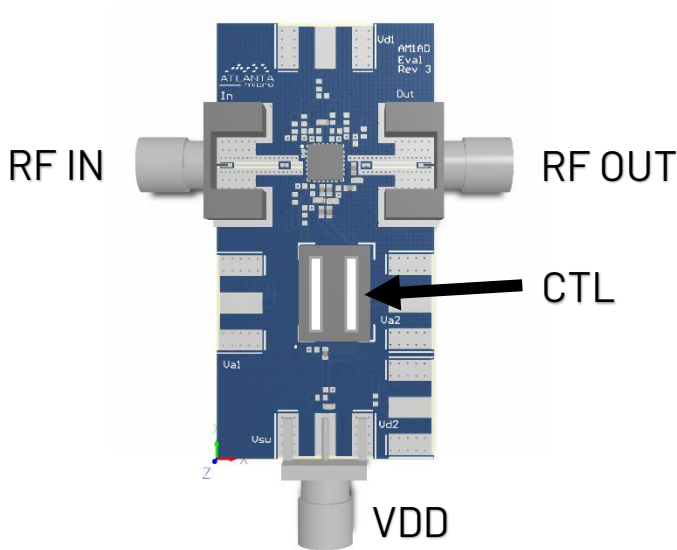
RECOMMENDED COMPONENT LIST (OR EQUIVALENT)

Part	Value	Part Number	Manufacturer
C1, C2	0.1 μ F	0402BB104KW500	Passives Plus
C3	0.1 μ F	0201BB104KW250	Passives Plus
C4	10,000 pF	GRM033R61E103KA12D	Murata
C5	0.1 μ F	GCM155R71H104KE02J	Murata
FB1, FB2	-	MMZ1005A222E	TDK

Notes:

1. DC blocking capacitors C1 – C3 should be high performance, low-loss, broadband capacitors for optimum performance.
2. Select control line RC filter values based on desired logic source decoupling and switching speed.
3. C3 and C4 should be placed as close to the AM1065 as possible to minimize PCB trace lengths. A 0201 package size is recommended to minimize stray PCB pad capacitance to ground.

EVALUATION PC BOARD



RELATED PARTS

Part Number		Description
AM1063-1	DC to 10 GHz	Gain Block
AM1063-2	DC to 10 GHz	Miniature Gain Block
AM1064-1	DC to 8 GHz	Gain Block
AM1064-2	DC to 8 GHz	Miniature Gain Block
AM1067	5 GHz to 20 GHz	Bypassable Gain Block
AM1073	DC to 8 GHz	Bidirectional / Bypassable Gain Block
AM1075	5 GHz to 26.5 GHz	Bypassable Gain Block
AM1077	5 GHz to 20 GHz	Bypassable Gain Block w/ Isolation State
AM1081	DC to 8 GHz	Bypassable Gain Block (Higher IP3)

PARTS ORDERING DETAILS

Description	Part Number
4mm 24 Lead QFN	AM1065
AM1065 Evaluation Board	AM1065 Eval
AM1065 in 0.95" x 1.13" x 0.6" RF-Shielded Module with Integrated Bias Tee and Field Replaceable SMA Connectors	AM1065-M

COMPONENT COMPLIANCE INFORMATION

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Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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